

Design and Validation of RF-MEMS Wide Band Phase Shifters in Harsh Environments

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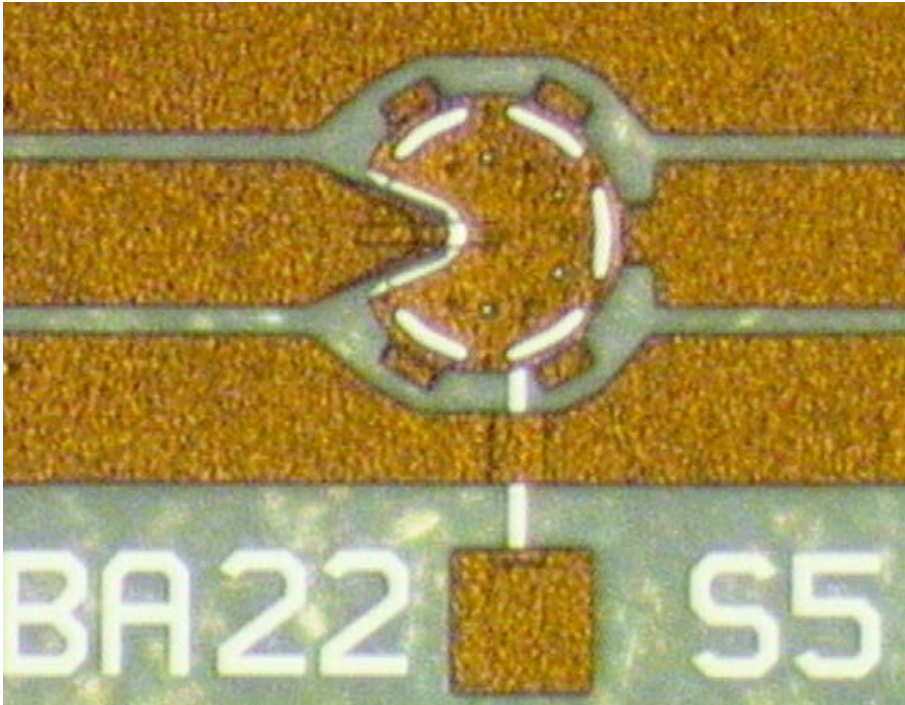
RF-MEMS Developments

- Phase shifters with RF-MEMS Ohmic switches
 - Low R_{on} – Low C_{off}
 - Control voltage 60 Volts – no power consumption
 - $T_{on} T_{off} \sim 4 \mu\text{sec}$
 - Reliability $> 10^8$ cycles – Power handling few Watts
- Fabrication at XLIM Laboratory
- Fabrication and flip-chip assembly up to Ka-Band
 - Filters
 - Phase shifters
- AirMems startup for the commercialization of RF-MEMS

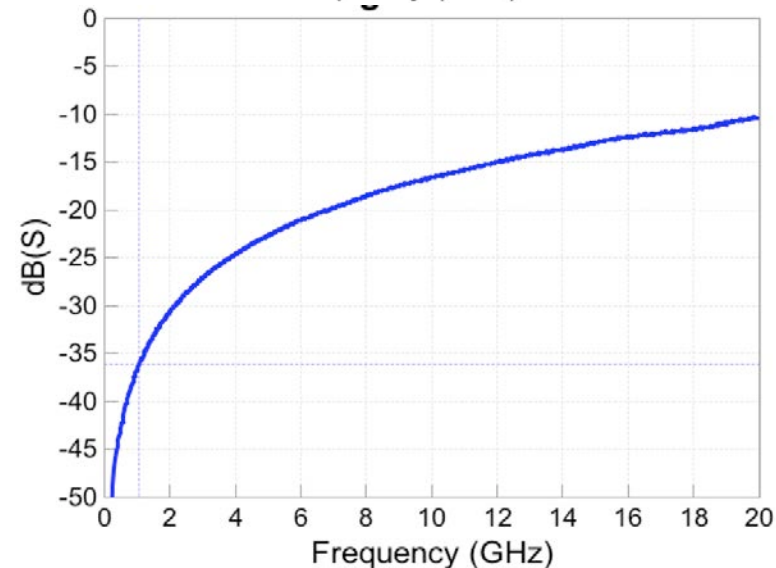
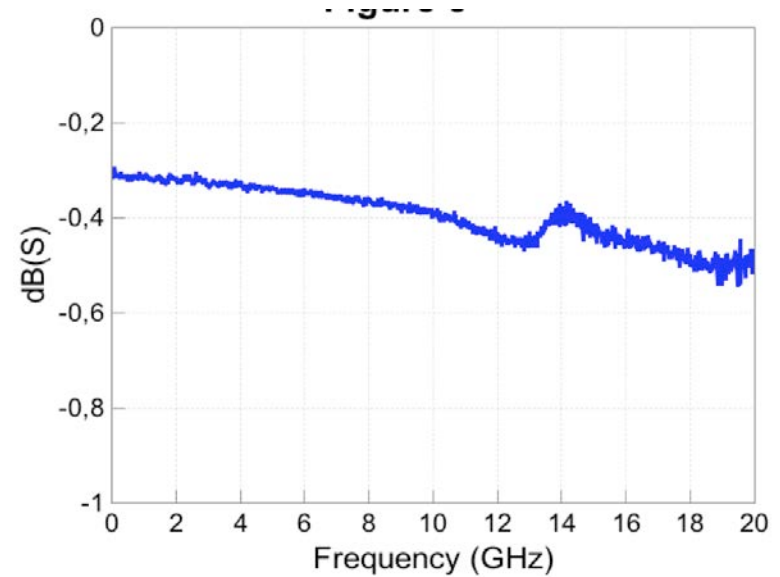
RF-MEMS Context

- Rapidly evolving technology
 - Integration into cell-phones is under way
- Defense applications are emerging
- Advanced experiments for space (MEMO) are under way

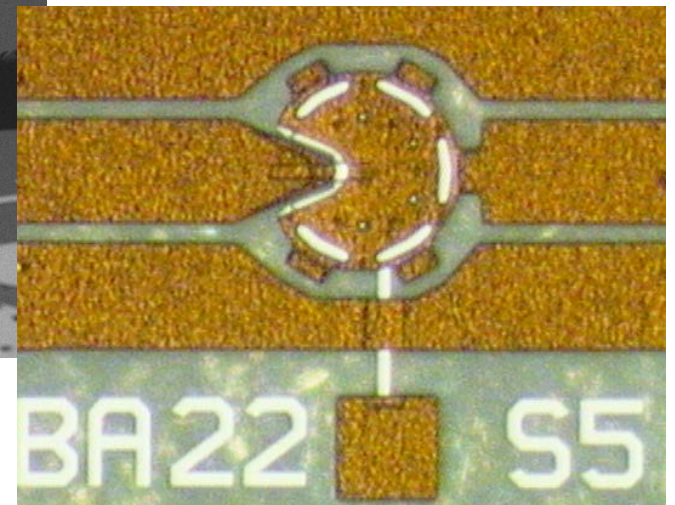
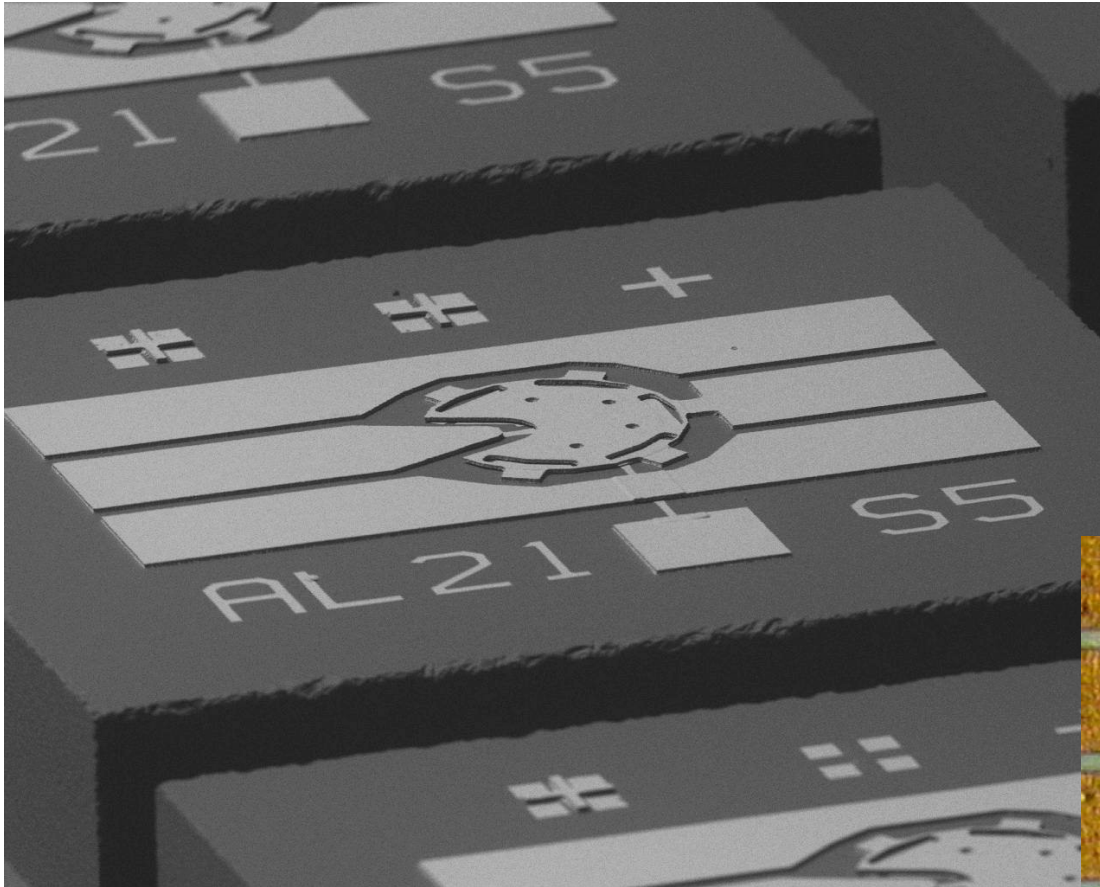
XLIM/Airmems RF-MEMS Switch



- Large contact force
- Low sensitivity to residual stress
- Temperature stable
- No dielectrics (Air gap switch)

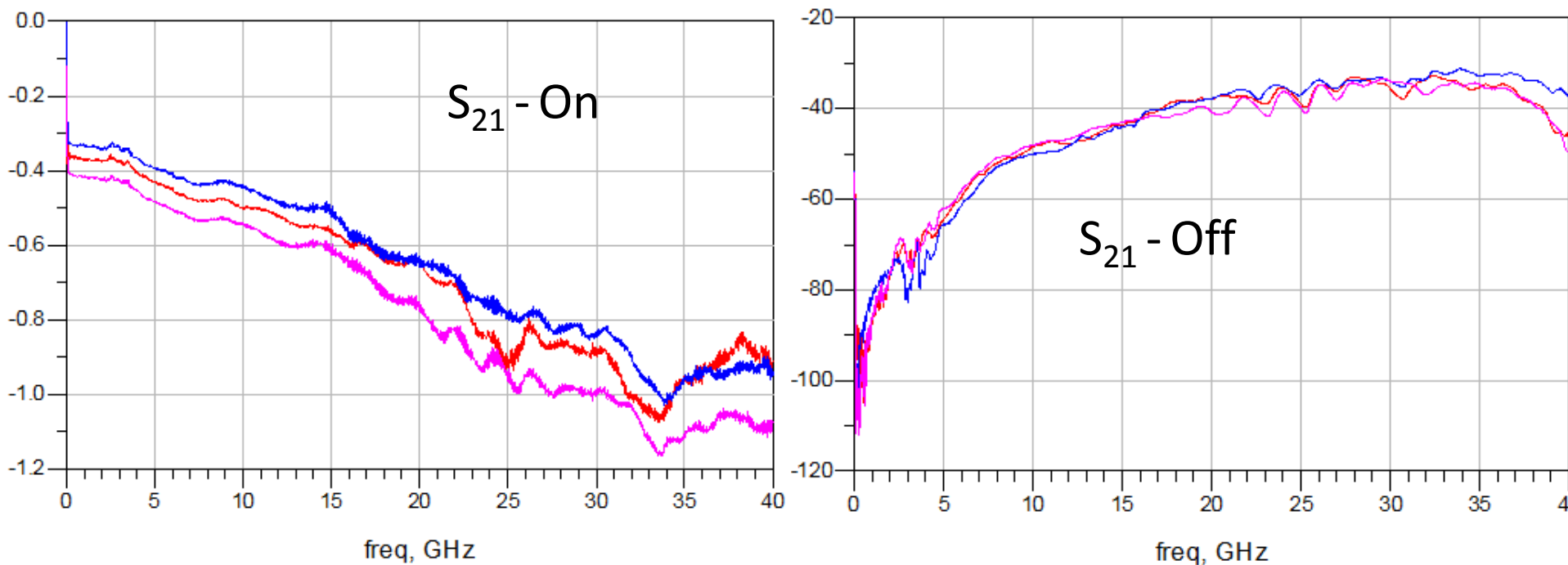


SEM View of XLIM Relay



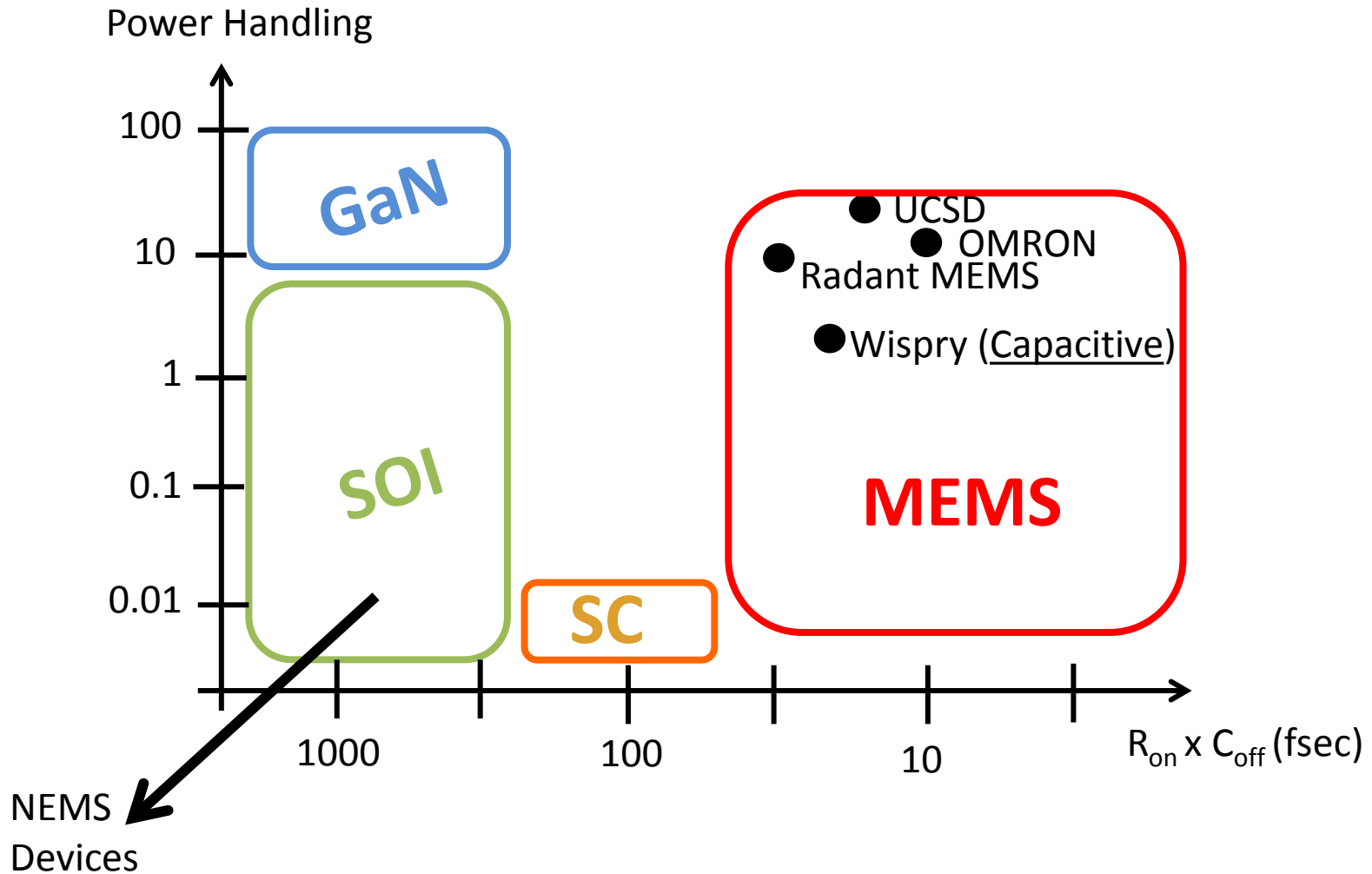
RF-MEMS Switch XLIM/ Airmems

- Series-Shunt arrangement



@ 10 GHz: 0.5 dB loss - > 50 dB isolation

RF-MEMS-RF and SC



Process



1 - Métal 1



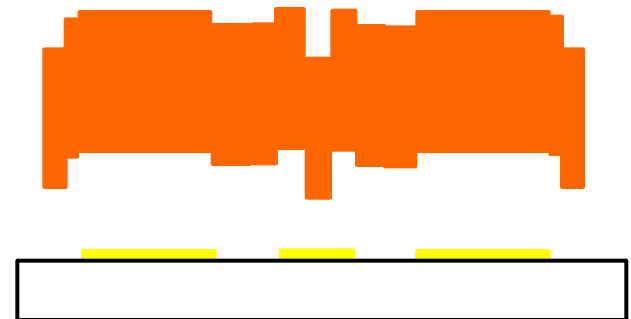
2 – Sacri 1 (dimple)



3 – Sacri 2



4 – Metal2



5 – Release

Reliability - Physics of Failure

- Dielectric Charging: Charge retention inside the dielectric layers of the actuator
- Actuator design: crucial in Ohmic RF-MEMS switches
- Contact metallurgy
- Creep: Thin film metals suffer from mechanical creep. This is causing actuation voltage shifting.

Space Vehicle Harsh Environment

Parameters :

- Bandwidth : 2.0 -3.0 GHz;
- SWR <1.5 on each input/output;
- Insertion loss : < 1dB;
- Power handling : 5 W;
- 4 states (0°,90°,180°, 270°) +/-2°.

The climatic environment :

- Temperature : -10°C to +70°C
- Hygrometry : 50% to 100%

The mechanical environment :

- Pyrotechnical shock : until Z1
- Sinusoidal vibration; - acceleration (until 100G)
- Overpressure (5 bar) or vacuum (10⁻⁵ bar);

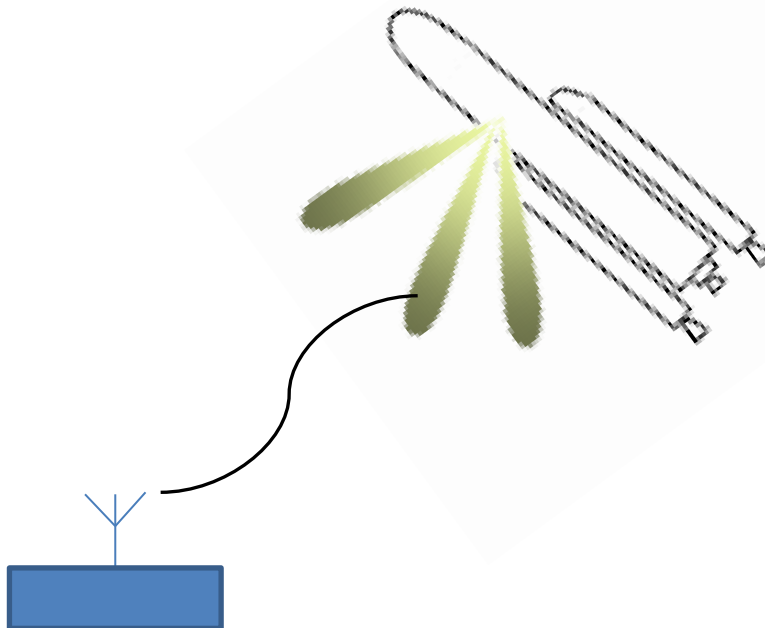
Electromagnetic environment :

- Lightning;
- Electrostatic discharge;
- Radio radar environment;
- Radiated and conducted susceptibility;



Objectives

- **Integrating electronically steerable antennas on launchers :**
 - Improved link budget
 - Decrease in power
 - Reduced volume embedded
- **Telemetry Applications :**
 - Knowledge of the internal behavior of the launcher by ground transmission functional parameters of the main components of the launcher and flight events.

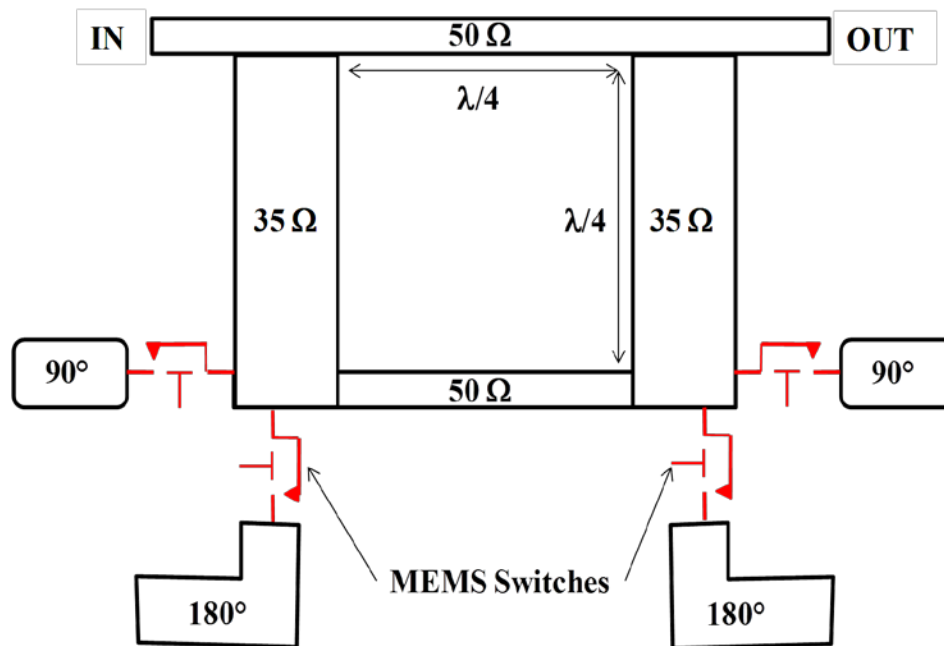


2.2 GHz Phase Shifters

- Hybrid Branch-line couplers have been chosen:
 - Low loss
 - Easy integration
- Fabrication is conducted on Alumina, with hybrid flip-chip integration of MEMS switches

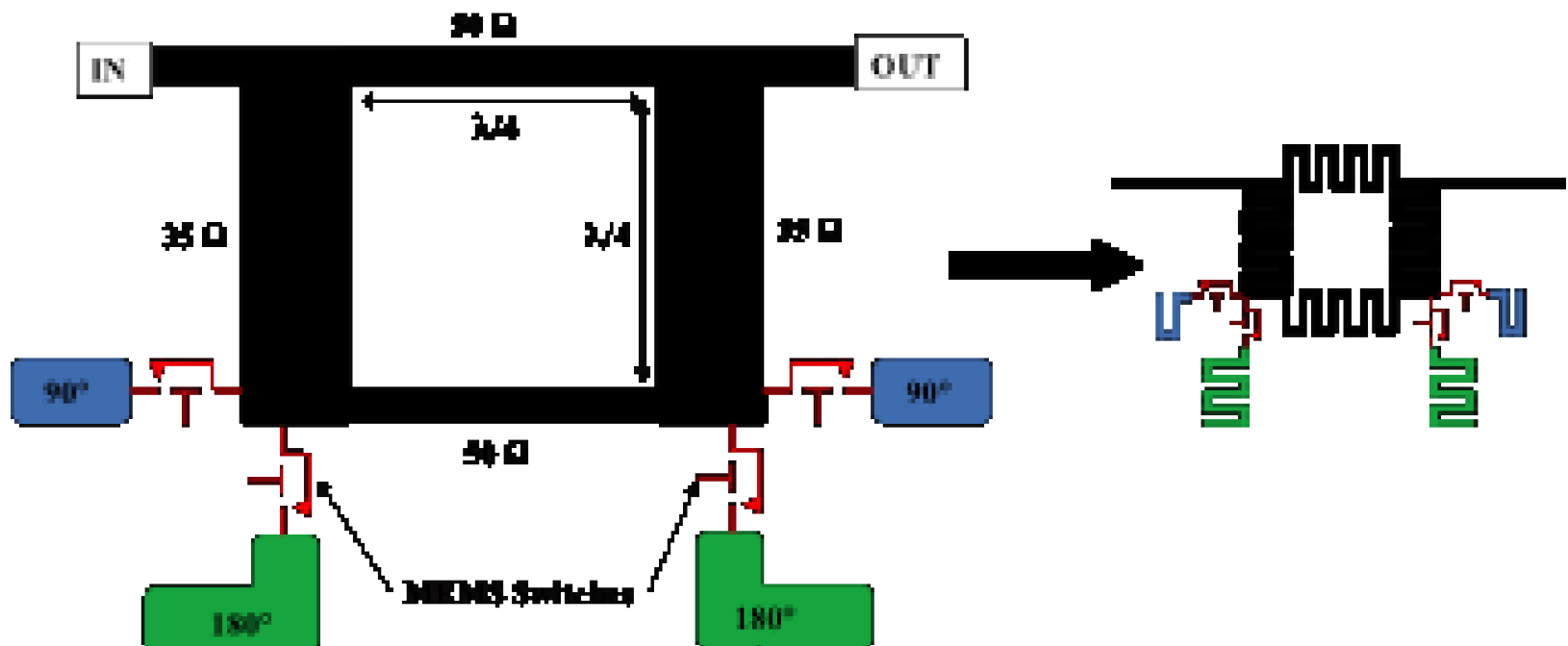
2.2 GHz Phase Shifters

- Operation – balanced design



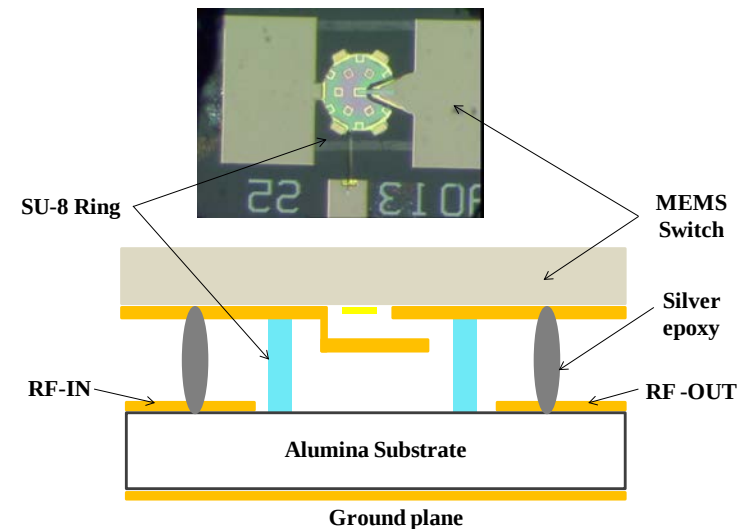
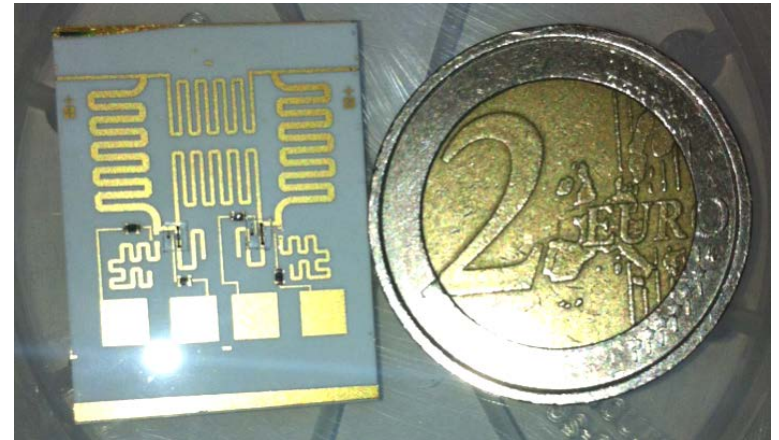
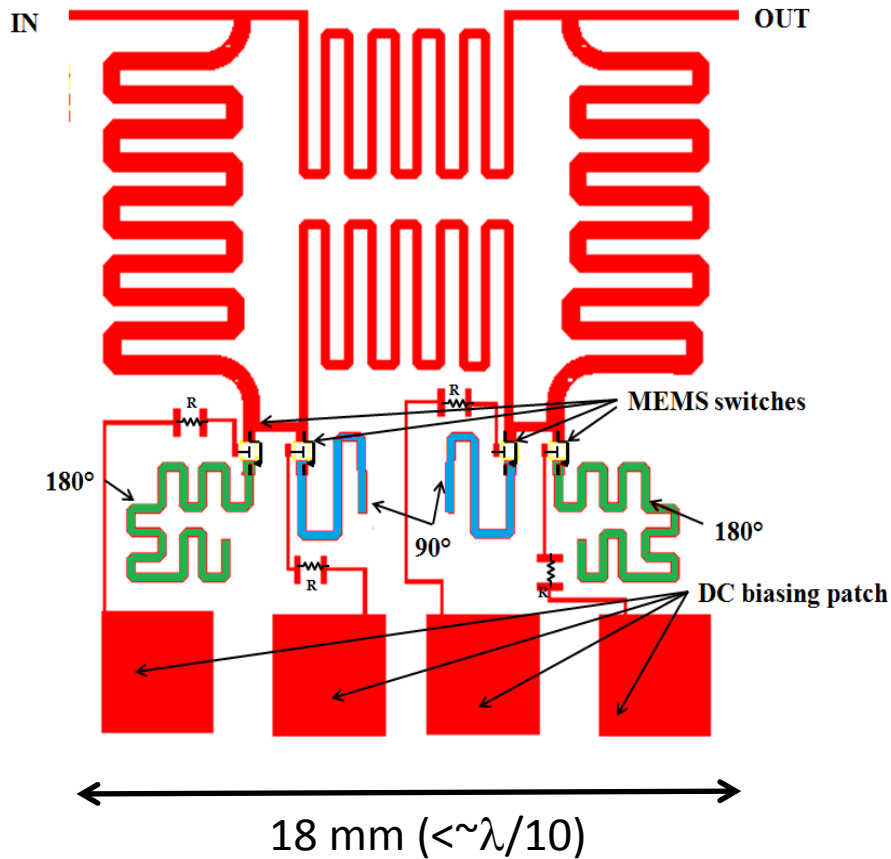
2.2 GHz Phase Shifters

- Operation and Meandered design

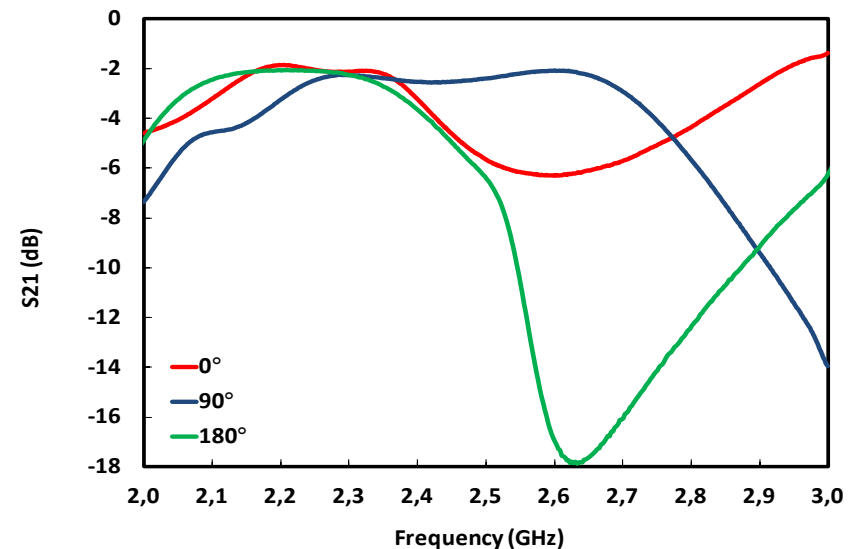
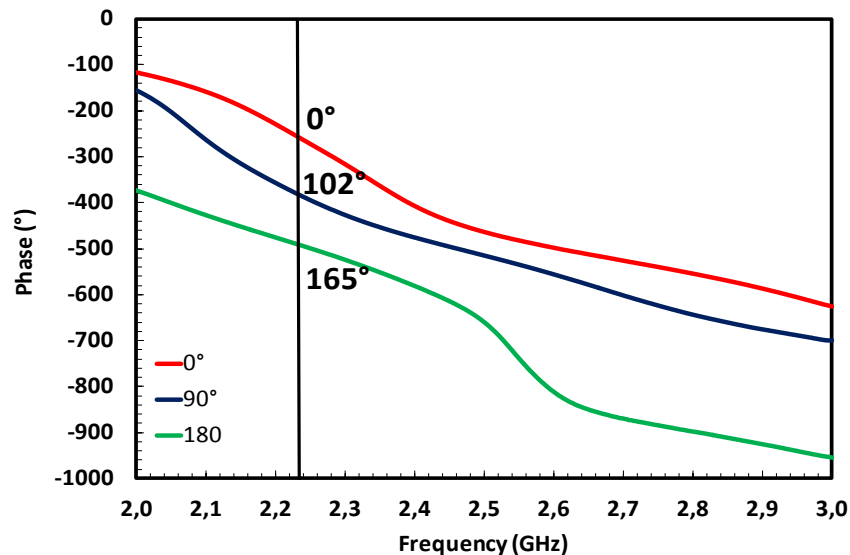
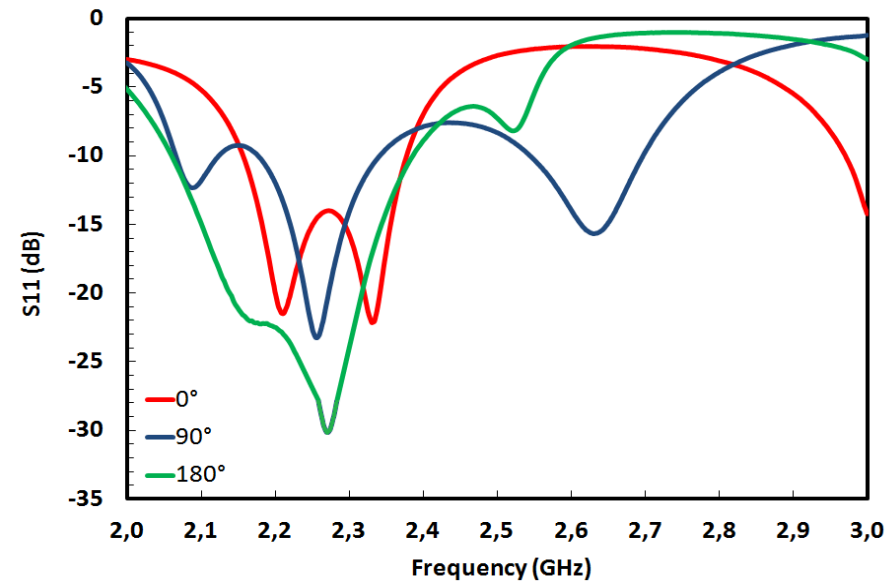
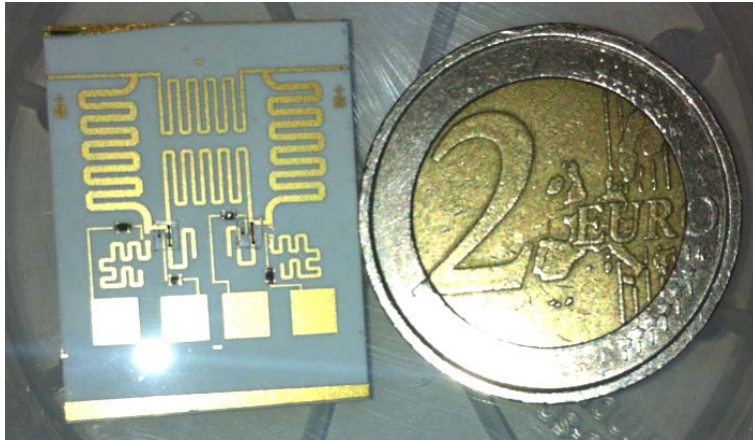


2.2 GHz Phase Shifter

- Final Layout



2.2 GHz Phase Shifter - Measurements



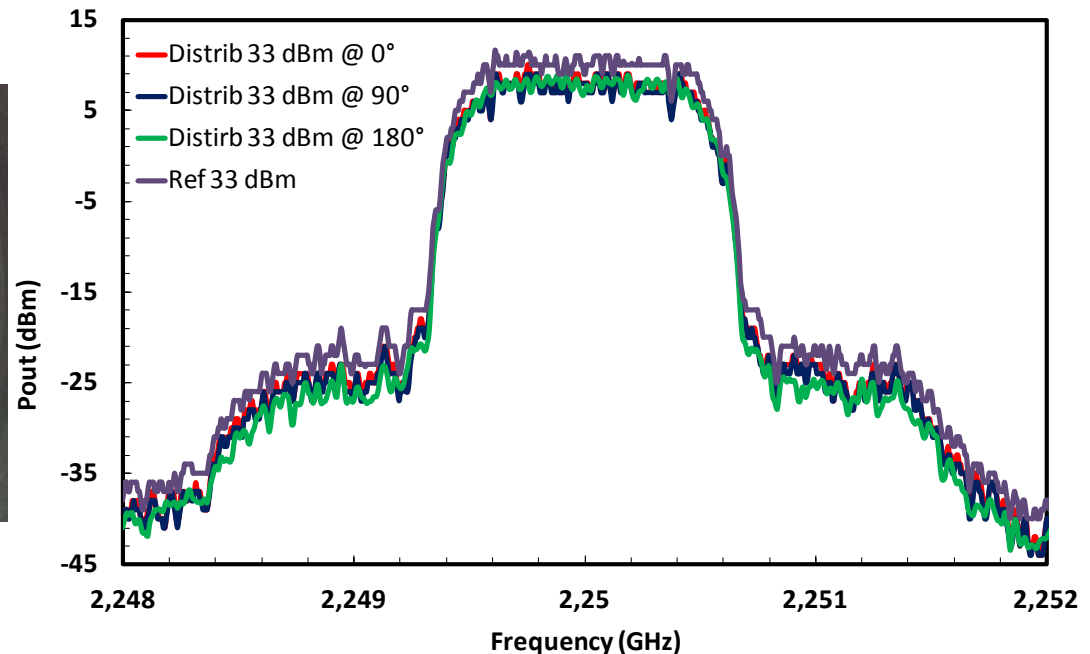
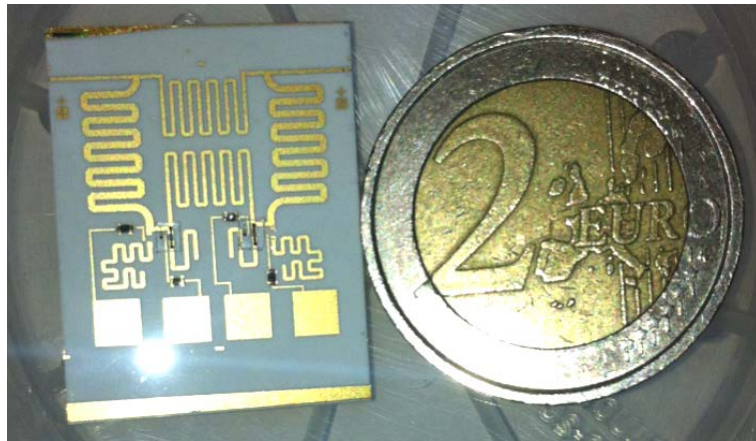
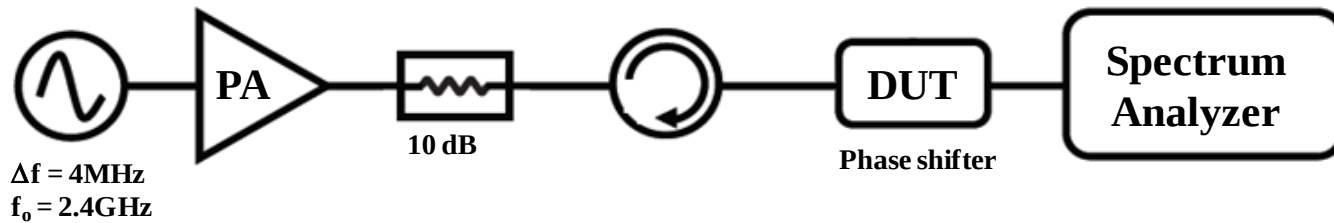
2.2 GHz Phase Shifter

Power Handling

Rohde & Scharwz
SMBV 100A
Vector Signal Generator

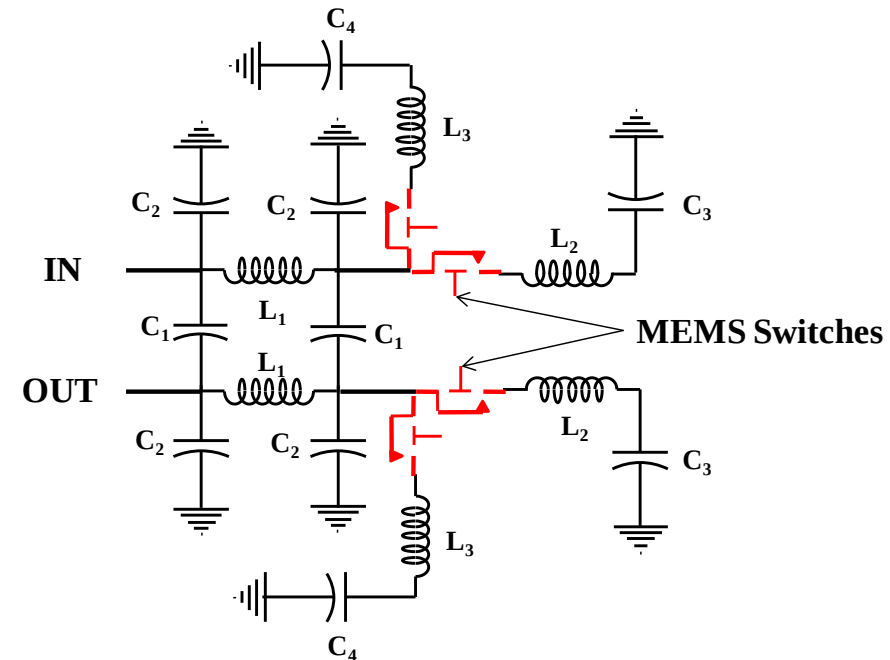
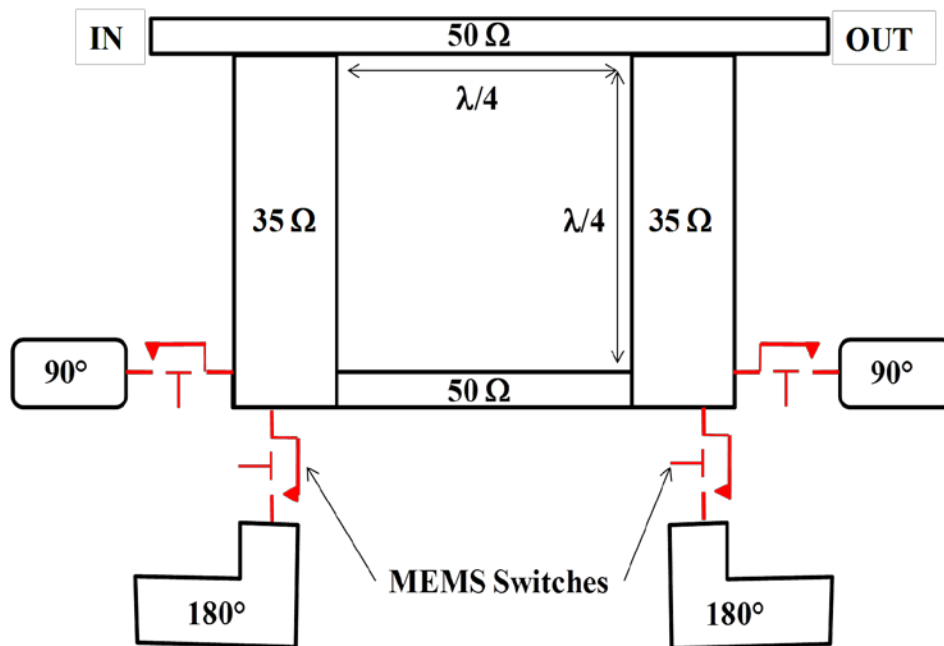
Power Amplifier
Bonn Elektronik
BLMA-1040-60D

Rohde & Scharwz
Signal Analyzer
3kHz-30GHz



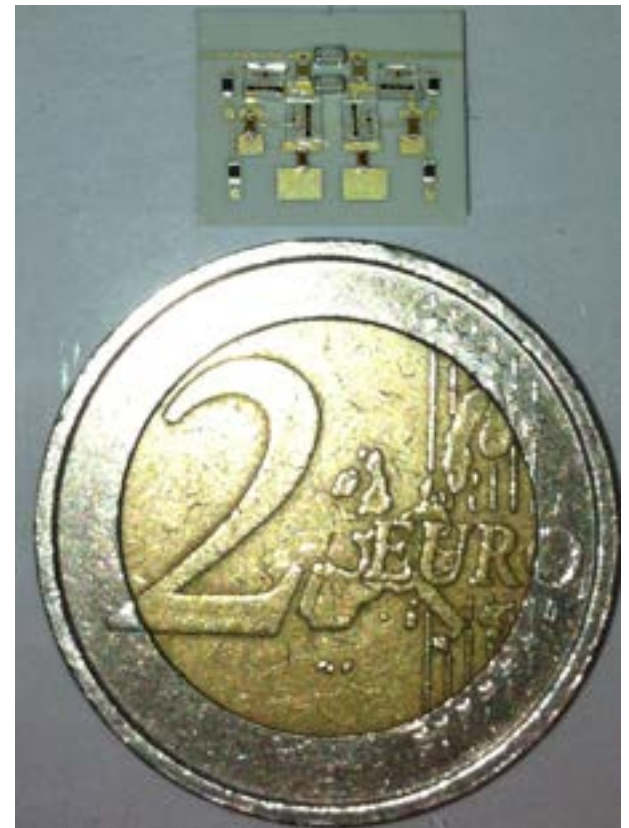
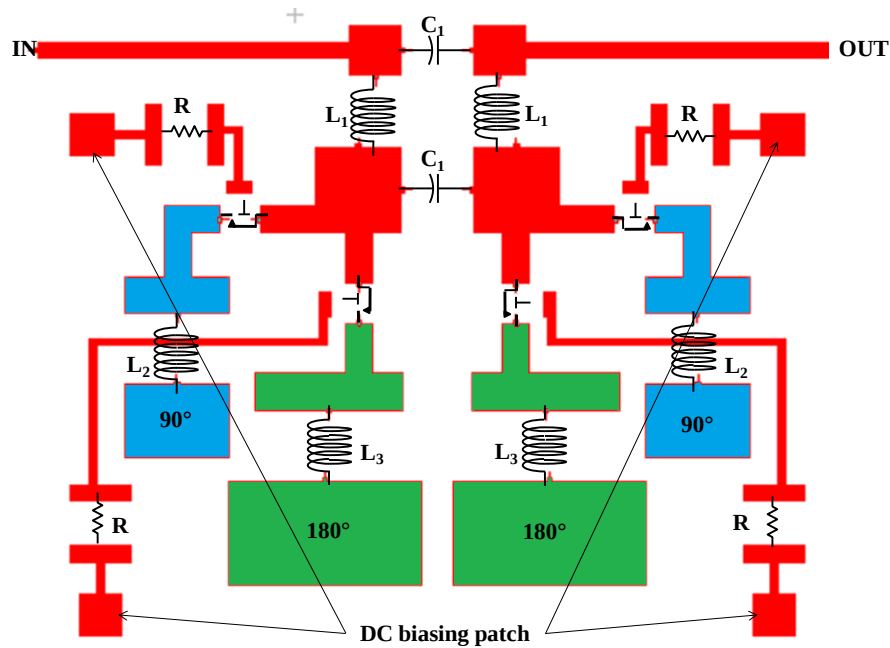
Lumped-Element Version

- Compact design



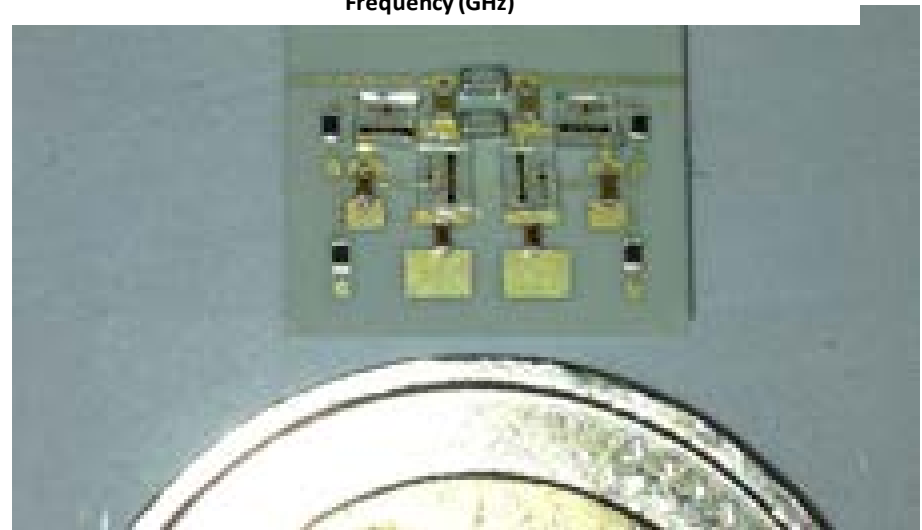
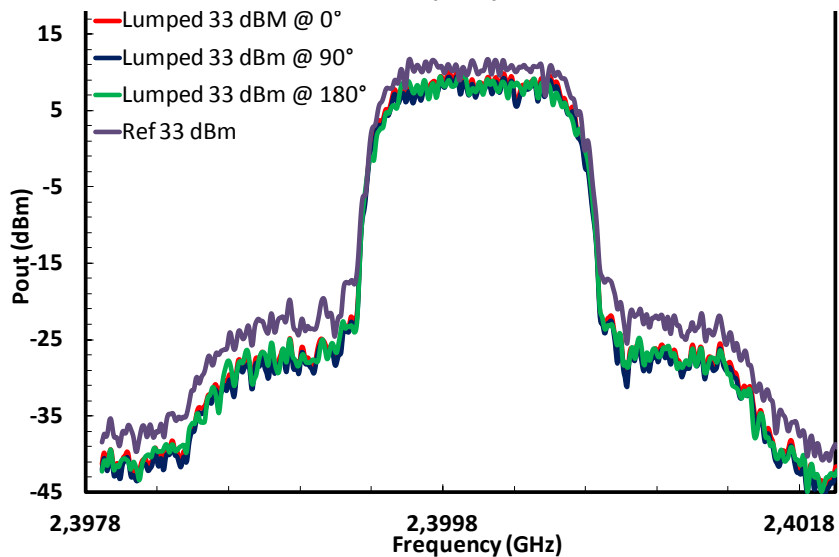
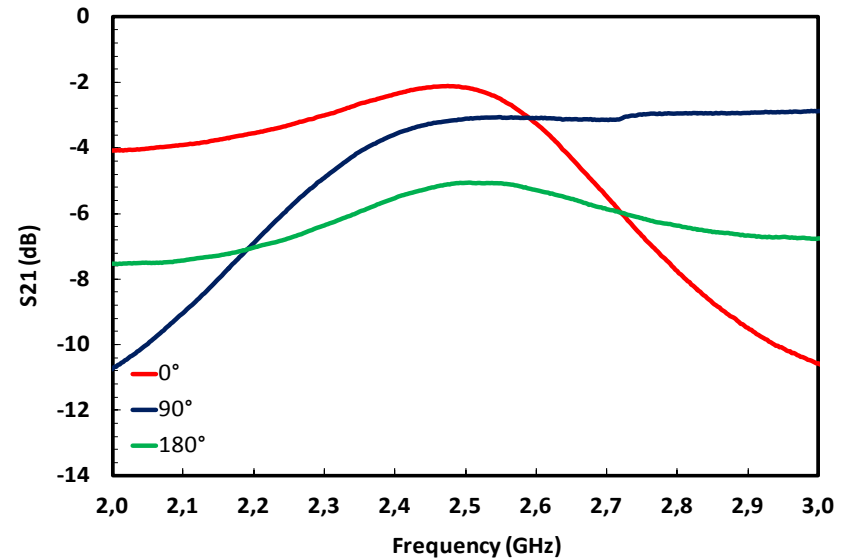
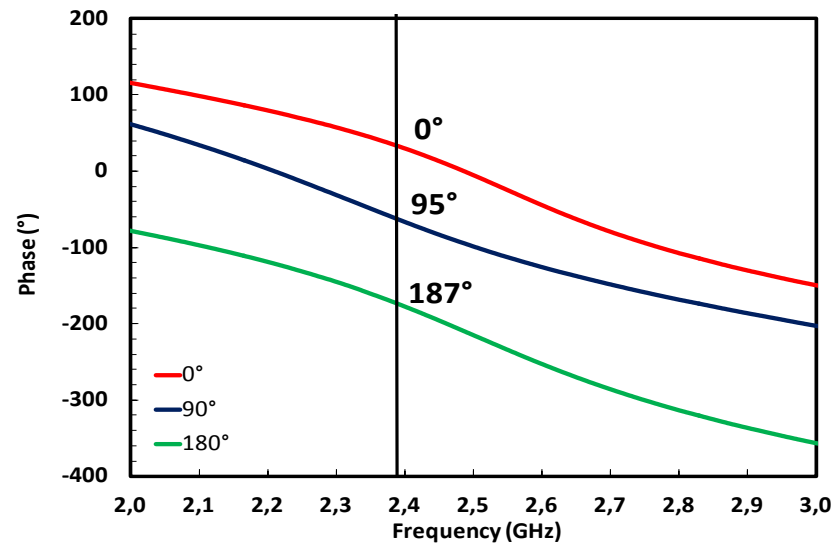
Lumped Element Version

- Final Layout

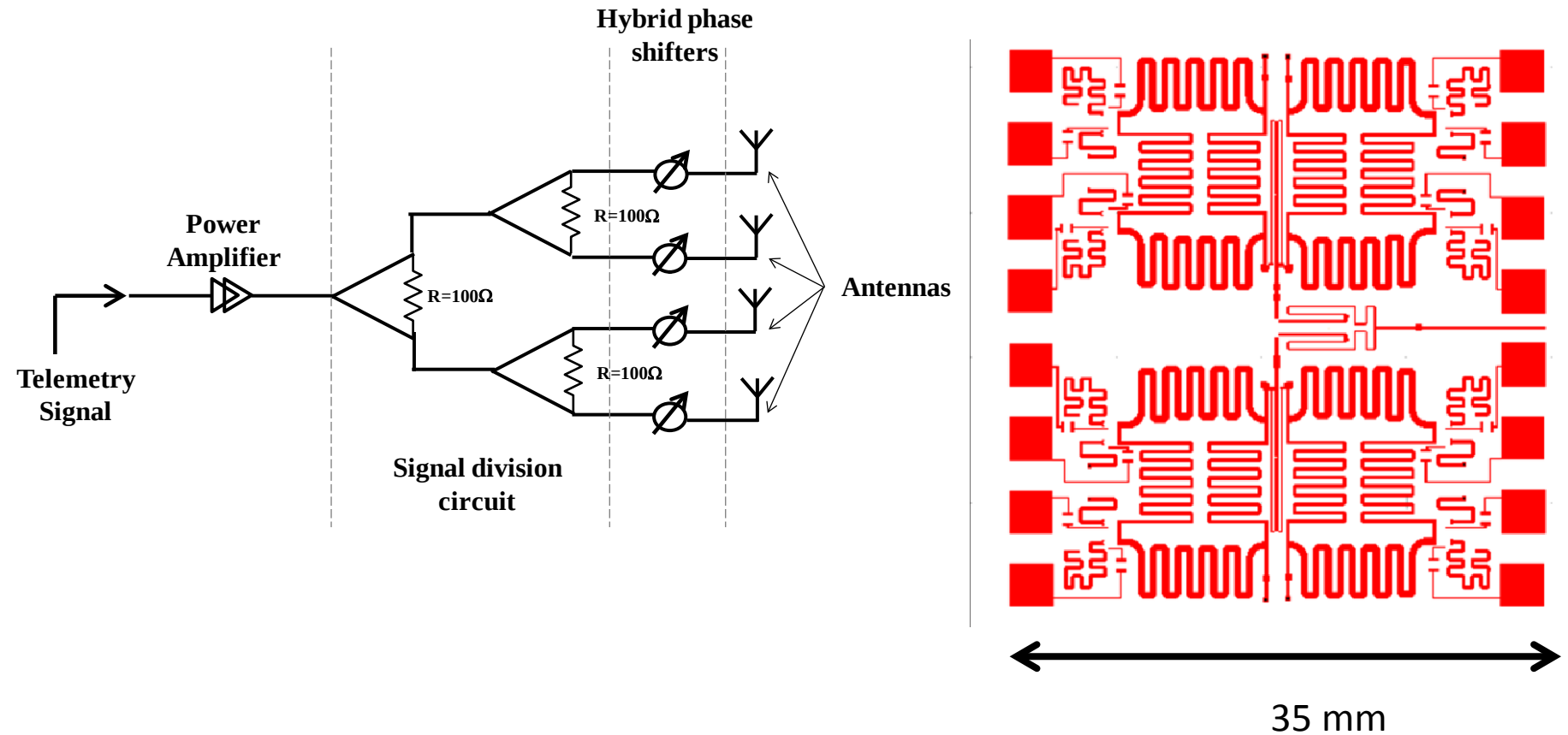


2.2 GHz Phase Shifters

Lumped-Element Version



Work in Progress - Integrated Chip



Conclusions

- RF-MEMS is an enabling technology for Low-loss and high linearity RF and microwave components
- Main applications:
 - Reconfigurable components at large (tuners-filters-antennas)
 - High power phase shifters
- Presented results:
 - High linearity ($>33\text{dBm}$) low loss ($<2\text{ dB}$) 2.2 GHz phase shifters
 - Flip chip assembly of RF-MEMS switches